imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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Photo Diode

Product No: MTD3010N

Peak Sensitivity Wavelength: 900nm

The MTD3010N is a photo diode in a TO-18 metal can domed package. It is well suited for high reliability and high speed applications.

FEATURES

- > Linearity of Ee vs IL
- > Low Dark Current / Metal Can Package
- > Narrow Angular Response
- > High Reliability in Demanding Environments

APPLICATIONS

- > Optical Switches
- > Edge Sensing
- > Fiber Optical Communications
- > Smoke Detectors



Ph

Absolute Maximum Ratings (Ta=25°C)

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ITEMS	SYMBOL	RATINGS	UNIT	lead-freé KC
Reverse Voltage	VR	30	V	
Power Dissipation	PD	100	mW	
Operating Temperature Range	Topr	-30 ~ +100	Co	
Storage Temperature Range	Tstg	-40 ~ +125	Co	
Junction Temperature	Tj	125	Co	
Lead Soldering Temperature*1	TIs	260	℃	

*1: Time 5 Sec max, Position: Up to 3mm from the body.

Electrical & Optical Characteristics (Ta = 25°C)

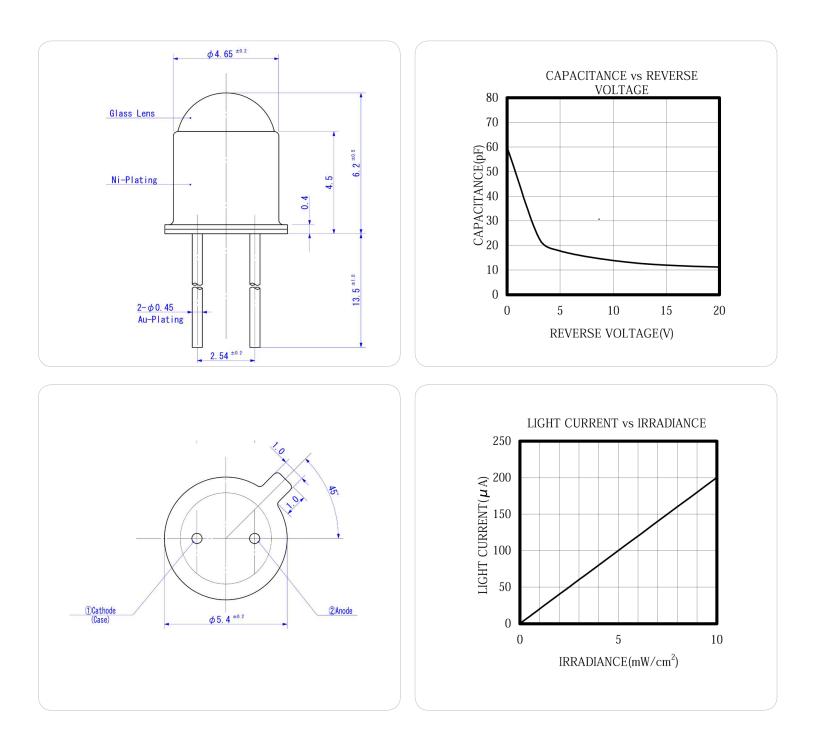
		N N	/			
ITEMS	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNIT
Open Circuit Voltage	Voc	Ee=5mW/cm ² *1	0.35			V
Light Current	IL	*1, *2		100		μA
Dark Current	ID	VR=10V			10	nA
Curve Factor	CF	Ee=5mW/cm ² *1	0.55			
Spectral Sensitivity	λ			400~1100		nm
Peak Sensitivity Wavelength	λp			900		nm
Responsivity	Rt	VR=0V, λ=450nm		0.18		A/W
Responsivity	Rt	VR=0V, λ=900nm		0.58		A/W
Angular Response	θ			±8		deg
Junction Capacitance	Cj	at 1MHz, V=0V		60	100	pF

*1: Color Temperature=2870°K Stardard Tungsten Lamp, *2: VR=10V, Ee=5mW/cm².

2011-07-20



Photo Diode Product No: MTD3010N

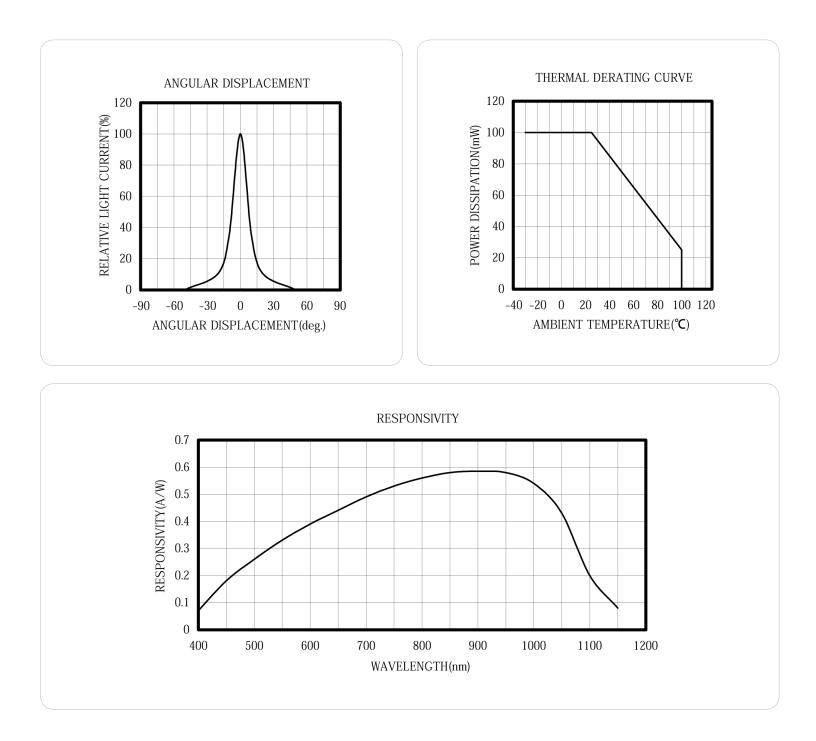


Unit: mm, Tolerance: ±0.2

2011-07-20



Photo Diode Product No: MTD3010N



The information contained herein is subject to change without notice.

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